Product data sheet

1 Product profile

1.1 General description

Two planar PIN diodes in common cathode configuration in an SOT23 small SMD plastic package.

1.2 Features and benefits

- · High voltage; current controlled
- · Low diode capacitance
- · Low series inductance
- AEC-Q101 qualified

1.3 Applications

RF attenuators and switches



Silicon PIN diode

2 Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	anode (a1)		
2	anode (a2)	3	3
3	common cathode	1 2	2 1 1 1 1

3 Ordering information

Table 2. Ordering information

Type number		Package					
		Name	Description	Version			
	BAP70-05	-	plastic surface-mounted package; 3 leads	SOT23			

4 Marking code

Table 3. Marking

Type number	Marking code			
BAP70-05	8K%			

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage	continuous voltage	-	50	V
I _F	forward current	continuous current	-	100	mA
P _{tot}	total power dissipation	T _{sp} ≤ 90 °C	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6 Thermal characteristics

Table 5. Thermal characteristics

Table 6. Thermal characteristics					
Symbol	Parameter	Conditions	Тур	Unit	
R _{th(j-sp)}	thermal resistance from junction to solder point		220	K/W	

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7 Characteristics

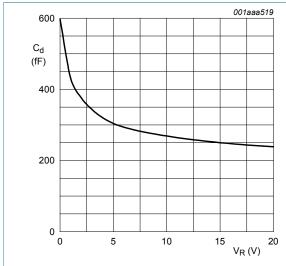
Table 6. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 50 mA	-	0.95	1.1	V
I _R	reverse current	V _R = 50 V	-	-	100	nA
C _d	diode capacitance	f = 1 MHz (see Figure 1)				
		V _R = 0 V	-	600	-	fF
		V _R = 1 V	-	430	-	fF
		V _R = 20 V	-	250	300	fF
r _D	diode forward resistance	f = 100 MHz (see <u>Figure 2</u>)				
		I _F = 0.5 mA	-	77	100	Ω
		I _F = 1 mA	-	40	50	Ω
		I _F = 10 mA	-	5.4	7	Ω
		I _F = 100 mA	-	1.4	1.9	Ω
τL	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	-	1.25	-	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	-	1.4	-	nΗ

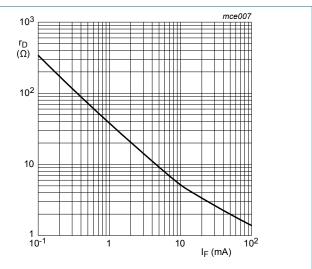
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8 Graphical data



f = 1 MHz; $T_j = 25 °C$.

Figure 1. Diode capacitance as a function of reverse voltage (typical values)

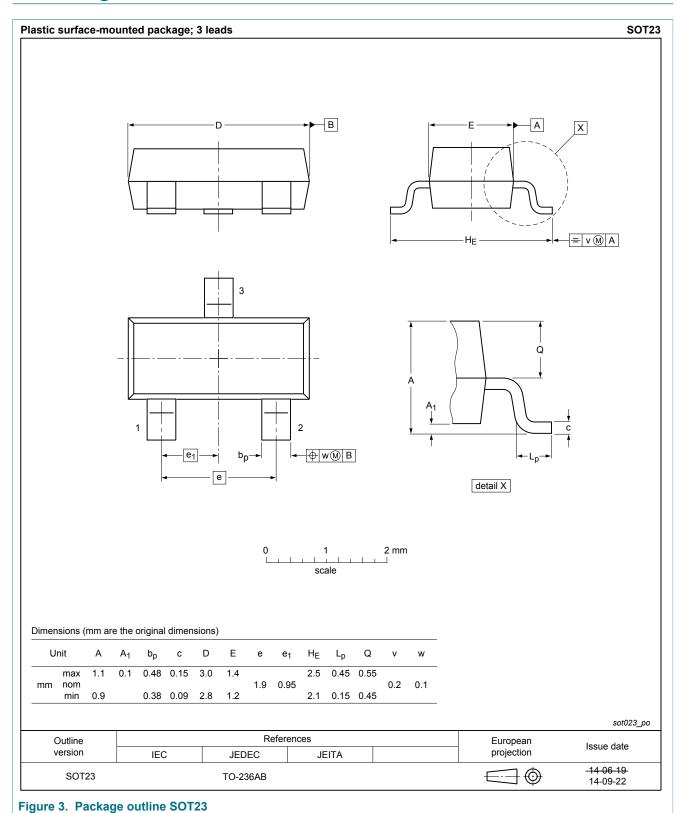


f = 100 MHz; $T_i = 25 \,^{\circ}\text{C}$.

Figure 2. Diode forward resistance as a function of forward current (typical values)

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9 Package outline



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10 Abbreviations

Table 7. Abbreviations

Acronym	Description
PIN	P-type, intrinsic, N-type
SMD	surface-mounted device
RF	radio frequency

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11 Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP70-05 v.6	20181211	Product data sheet	-	BAP70-05 v.5
Modifications:	adapted marking	tures and benefits" has been u code nation" pages have been updat		
BAP70-05 v.5	20140307	Product data sheet		BAP70-05 v.4
BAP70-05 v.4	20140127	Product data sheet	-	BAP70-05 v.3
BAP70-05 v.3	20070405	Product data sheet	-	BAP70-05 v.2
BAP70-05 v.2	20061221	Product data sheet	-	BAP70-05 v.1
BAP70-05 v.1 (9397 750 12811)	20040405	Product data sheet	-	-

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12 Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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